Configurable Multifunction Gate

NL7SZ57

The NL7SZ57 is an advanced high-speed CMOS multifunction gate. The device allows the user to choose logic functions AND, OR, NAND, NOR, XNOR, INVERT and BUFFER. The device has Schmitt-trigger inputs, thereby enhancing noise immunity.

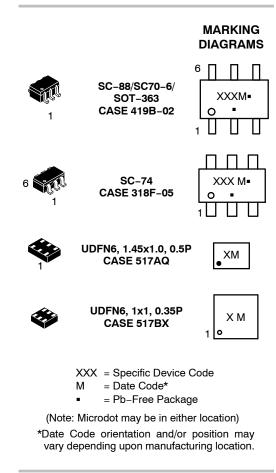
Features

- Designed for 1.65 V to 5.5 V V_{CC} Operation
- 3.3 ns t_{PD} at $V_{CC} = 5 V (Typ)$
- Inputs/Outputs Overvoltage Tolerant up to 5.5 V
- I_{OFF} Supports Partial Power Down Protection
- Sink 24 mA at 3.0 V
- Chip Complexity < 100 FETs
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



ON Semiconductor®

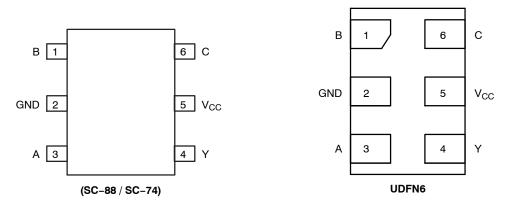
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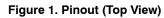


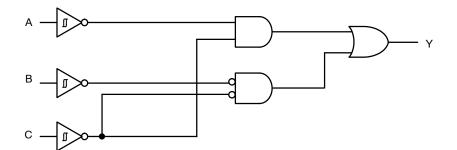
ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

NL7SZ57









PIN ASSIGNMENT

Pin	Function
1	В
2	GND
3	А
4	Y
5	V _{CC}
6	С

FUNCTION TABLE*

	Input			
А	В	С	Y	
L	L	L	Н	
L	L	Н	L	
L	Н	L	Н	
L	Н	Н	Н	
Н	L	L	L	
Н	L	Н	L	
Н	Н	L	L	
Н	Н	Н	Н	

*To select a logic function, please refer to "Logic Configurations section".

NL7SZ57

LOGIC CONFIGURATIONS

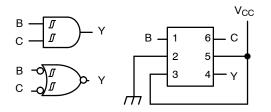


Figure 3. 2-Input AND (When A = "H")

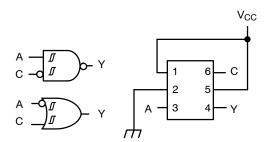


Figure 5. 2–Input NAND with Input C Inverted (When B = "H")

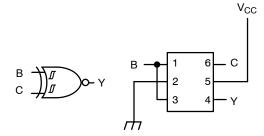


Figure 7. 2–Input XNOR (When A = B)

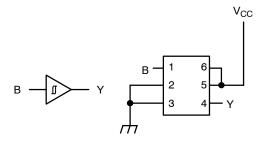


Figure 9. Buffer (When A = "L" and C = "H")

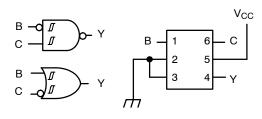


Figure 4. 2–Input NAND with input B inverted (When A = "L")

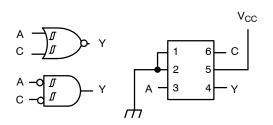


Figure 6. 2-Input NOR (When B = "L")

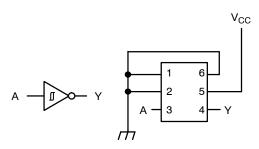


Figure 8. Inverter (When B = C = "L")

MAXIMUM RATINGS

Symbol	Para	neter	Value	Unit	
V _{CC}	DC Supply Voltage	SC-88 (NLV) SC-88, SC-74, UDFN6	-0.5 to +7.0 -0.5 to +6.5	V	
V _{IN}	DC Input Voltage	SC-88 (NLV) SC-88, SC-74, UDFN6	-0.5 to +7.0 -0.5 to +6.5	V	
V _{OUT}	DC Output Voltage SC-88 (NLV)	Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V _{CC} = 0 V)	-0.5 to V _{CC} + 0.5 -0.5 to +7.0 -0.5 to +7.0	V	
	DC Output Voltage SC-88, SC-74, UDFN6	Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V _{CC} = 0 V)	-0.5 to V _{CC} + 0.5 -0.5 to +6.5 -0.5 to +6.5	V	
I _{IK}	DC Input Diode Current	V _{IN} < GND	-50	mA	
Ι _{ΟΚ}	DC Output Diode Current	DC Output Diode Current V _{OUT} < GND			
I _{OUT}	DC Output Source/Sink Current	±50	mA		
I _{CC} or I _{GND}	DC Supply Current per Supply Pin or Gr	±100	mA		
T _{STG}	Storage Temperature Range		-65 to +150	°C	
ΤL	Lead Temperature, 1 mm from Case for	10 Secs	260	°C	
TJ	Junction Temperature Under Bias		+150	°C	
θ_{JA}	Thermal Resistance (Note 2)	SC-88 SC-74 UDFN6	377 320 154	°C/W	
P _D	Power Dissipation in Still Air	SC-88 SC-74 UDFN6	332 390 812	mW	
MSL	Moisture Sensitivity		Level 1		
F _R	Flammability Rating Oxygen	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in		
V _{ESD}	ESD Withstand Voltage (Note 3)	Human Body Mode Charged Device Model (NLV) Charged Device Model	>2000 >200 N/A	V	
ILATCHUP	Latchup Performance (Note 4)	(NLV)	±500 ±100	mA	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. Applicable to devices with outputs that may be tri-stated.

 Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow per JESD51-7.
CDM tested to EIA/JESD22-C101-F. JEDEC recommends that ESD qualification to EIA/JESD22-A115-A (Machine Model) be discontinued per JEDEC/JEP172A.4. Tested to EIA/JESD78 Class II.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V _{CC}	Positive DC Supply Voltage	1.65	5.5	V
V _{IN}	DC Input Voltage	0	5.5	V
V _{OUT}		ode (High or Low State)0Gri-State Mode (Note 1)0Down Mode (V _{CC} = 0 V)0	V _{CC} 5.5 5.5	V
T _A	Operating Free-Air Temperature	-55	+125	°C
t _r , t _f	Input Rise or Fall Rate	$\begin{array}{c} V_{CC} = 1.65 \ V \ to \ 1.95 \ V \\ V_{CC} = 2.3 \ V \ to \ 2.7 \ V \\ V_{CC} = 3.0 \ V \ to \ 3.6 \ V \\ V_{CC} = 4.5 \ V \ to \ 5.5 \ V \end{array} \begin{array}{c} 0 \\ 0 \\ \end{array}$	No Limit No Limit No Limit No Limit	nS/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

Symbol Parameter			V _{cc}	-	T _A = 25°(C		c ≤ T _A 85°C	-55°C ≤ T _A ≤ 125°C		
	Condition	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit	
V _T +	Positive Input		1.65	-	-	1.4	-	1.4	-	1.4	V
	Threshold Voltage		2.3	-	-	1.8	-	1.8	-	1.8	
			3.0	-	-	2.2	-	2.2	-	2.2	
			4.5	-	-	3.1	-	3.1	-	3.1	
			5.5	-	-	3.6	-	3.6	-	3.6	
V _T -	Negative Input		1.65	0.2	-	-	0.2	-	0.2	-	V
	Threshold Voltage		2.3	0.4	-	-	0.4	-	0.4	-	
			3.0	0.6	-	-	0.6	-	0.6	-	
			4.5	1.0	-	-	1.0	-	1.0	-	
			5.5	1.2	-	-	1.2	-	1.2	-	
V _H	Input Hysteresis		1.65	0.1	0.48	0.9	0.1	0.9	0.1	-	V
	Voltage		2.3	0.25	0.75	1.1	0.25	1.1	0.25	-	
			3	0.4	0.93	1.2	0.4	1.2	0.4	-	
			4.5	0.6	1.2	1.5	0.6	1.5	0.6	-	
			5.5	0.7	1.4	1.7	0.7	1.7	0.7	-	
V _{OH}	High-Level Output Voltage	I _{OH} = –50 μA	1.65 to 5.5	V _{CC} - 0.1	V _{CC}	-	V _{CC} - 0.1	-	V _{CC} - 0.1	-	V
	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -4 mA	1.65	1.20	1.52	-	1.20	-	1.20	-	
		I _{OH} = -8 mA	2.3	1.9	2.1	-	1.9	-	1.9	-	
		I _{OH} = -16 mA	3	2.4	2.7	-	2.4	-	2.4	-	
		I _{OH} = -24 mA	3	2.3	2.5	-	2.3	-	2.3	-	
		I _{OH} = -32 mA	4.5	3.8	4	-	3.8	-	3.8	-	
V _{OL}	Low-Level Output Voltage	I _{OL} = 100 μA	1.65 to 5.5	_	-	0.1	-	0.1	-	0.1	V
	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 4 mA	1.65	-	0.08	0.45	-	0.45	-	0.45	
		I _{OL} = 8 mA	2.3	-	0.2	0.3	-	0.3	-	0.4	
		I _{OL} = 16 mA	3	-	0.28	0.4	-	0.4	-	0.5	
		I _{OL} = 24 mA	3	-	0.38	0.55	-	0.55	-	0.55	
		I _{OL} = 32 mA	4.5	-	0.42	0.55	-	0.55	-	0.65	
I _{IN}	Input Leakage Current	V _{IN} = 5.5 V or GND	1.65 to 5.5	_	-	+0.1	-	+1.0	-	+1.0	μΑ
I _{OFF}	Power Off Leakage Current	V _{IN} = 5.5 V or V _{OUT} = 5.5 V	0	-	-	1.0	-	10	-	10	μA
ICC	Quiescent Supply Current	V _{IN} = 5.5 V or GND	5.5	-	-	1.0	-	10	-	10	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

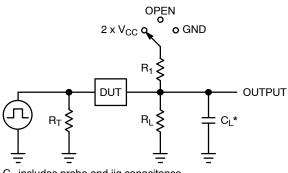
AC ELECTRICAL CHARACTERISTICS

				1	Γ _A = 25°0	•		s ≤ T _A 5°C		≤ T _A 25°C	
Symbol	Parameter	Condition	V _{CC} (V)	Min	Тур	Max	Min	Max	Min	Max	Unit
t _{PLH} , Propagation Delay, t _{PHL} (A or B or C) to Y (Figures 10 and 11)	$\begin{array}{l} R_{L} = 1 \ k\Omega, \\ C_{L} = 30 \ pF \end{array}$	1.65 to 1.95	-	8.6	14.4	1	14.4	-	14.4	ns	
	R _L = 500 Ω, CL = 30 pF	2.3 to 2.7	-	5.1	8.3	-	8.3	-	8.3		
		$R_L = 500 \Omega$,	3.0 to 3.6	-	3.9	6.3	-	6.3	_	6.3	
		C _L ⁻ = 50 pF	4.5 to 5.5	-	3.3	5.1	-	5.1	-	5.1	

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C _{IN}	Input Capacitance	V_{CC} = 5.5 V, V_{IN} = 0 V or V_{CC}	2.5	pF
C _{OUT}	Output Capacitance	V_{CC} = 5.5 V, V_{IN} = 0 V or V_{CC}	4.0	pF
C _{PD}	Power Dissipation Capacitance (Note 5)	10 MHz, V_{CC} = 3.3 V, V_{IN} = 0 V or V_{CC} 10 MHz, V_{CC} = 5.0 V, V_{IN} = 0 V or V_{CC}	16 19.5	pF

5. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$. C_{PD} is used to determine the no-load dynamic power consumption; $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$.

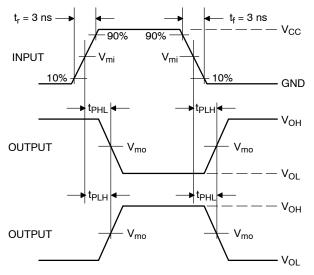


Switch Position	C _L , pF	R_L, Ω	R ₁ , Ω		
Open	See AC Characteristics Table				
$2 \times V_{CC}$	50	500	500		
GND	50	500	500		
	Position Open 2 x V _{CC}	Position See AC Character Open See AC Character 2 x V _{CC} 50	Position Image: Constraint of the set of the se		

X = Don't Care

 C_L includes probe and jig capacitance R_T is Z_{OUT} of pulse generator (typically 50 $\Omega)$ f = 1 MHz

Figure 10. Test Circuit



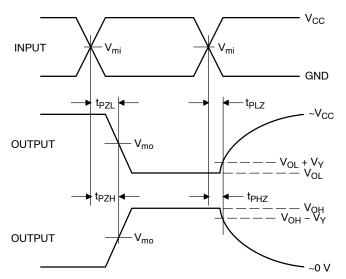


Figure 11. Switching Waveforms

		V _m		
V _{CC} , V	V _{mi} , V	t _{PLH} , t _{PHL}	t _{PZL} , t _{PLZ} , t _{PZH} , t _{PHZ}	V _Y , V
1.65 to 1.95	V _{CC} / 2	V _{CC} / 2	V _{CC} / 2	0.15
2.3 to 2.7	V _{CC} / 2	V _{CC} / 2	V _{CC} / 2	0.15
3.0 to 3.6	V _{CC} / 2	V _{CC} / 2	V _{CC} / 2	0.3
4.5 to 5.5	V _{CC} / 2	V _{CC} / 2	V _{CC} / 2	0.3

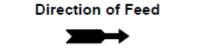
ORDERING INFORMATION

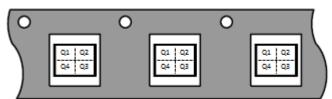
Device	Package			Shipping [†]
NL7SZ57DFT2G	SC-88 (Pb-Free)	MN	Q4	3000 / Tape & Reel
NLV7SZ57DFT2G*	SC–88 (Pb–Free)	MN	Q4	3000 / Tape & Reel
NL7SZ57DBVT1G	SC–74 (Pb–Free)	AL	Q4	3000 / Tape & Reel
NL7SZ57MU1TCG (In Development)	UDFN6, 1.45 x 1.0, 0.5P (Pb-Free)	TBD	Q4	3000 / Tape & Reel
NL7SZ57MU3TCG (In Development)	UDFN6, 1.0 x 1.0, 0.35P (Pb-Free)	P (Rotated 270° CW)	Q4	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. *NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP

Capable.

Pin 1 Orientation in Tape and Reel

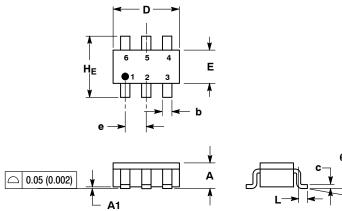




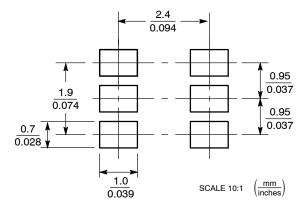




SCALE 2:1



SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

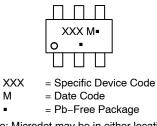
NOTES:

SC-74 CASE 318F-05 **ISSUE N**

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH
- CONTROLING DIMENSION: INCH. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM З.
- THICKNESS OF BASE MATERIAL. 4. 318F-01, -02, -03, -04 OBSOLETE. NEW STANDARD 318F-05.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.90	1.00	1.10	0.035	0.039	0.043
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.25	0.37	0.50	0.010	0.015	0.020
С	0.10	0.18	0.26	0.004	0.007	0.010
D	2.90	3.00	3.10	0.114	0.118	0.122
Е	1.30	1.50	1.70	0.051	0.059	0.067
e	0.85	0.95	1.05	0.034	0.037	0.041
L	0.20	0.40	0.60	0.008	0.016	0.024
HE	2.50	2.75	3.00	0.099	0.108	0.118
θ	0°	-	10°	0°	-	10°

GENERIC **MARKING DIAGRAM***



(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present.

STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:	STYLE 6:
PIN 1. CATHODE	PIN 1. NO CONNECTION	PIN 1. EMITTER 1	PIN 1. COLLECTOR 2	PIN 1. CHANNEL 1	PIN 1. CATHODE
2. ANODE	2. COLLECTOR	2. BASE 1	2. EMITTER 1/EMITTER 2	2. ANODE	2. ANODE
3. CATHODE	3. EMITTER	3. COLLECTOR 2	3. COLLECTOR 1	3. CHANNEL 2	3. CATHODE
4. CATHODE	4. NO CONNECTION	4. EMITTER 2	4. EMITTER 3	4. CHANNEL 3	4. CATHODE
5. ANODE	5. COLLECTOR	5. BASE 2	5. BASE 1/BASE 2/COLLECTOR 3	5. CATHODE	5. CATHODE
6. CATHODE	6. BASE	6. COLLECTOR 1	6. BASE 3	6. CHANNEL 4	6. CATHODE
STYLE 7:	STYLE 8:	STYLE 9:	STYLE 10:	STYLE 11:	E
PIN 1. SOURCE 1	PIN 1. EMITTER 1	PIN 1. EMITTER 2	PIN 1. ANODE/CATHODE	PIN 1. EMITTER	
2. GATE 1	2. BASE 2	2. BASE 2	2. BASE	2. BASE	
3. DRAIN 2	3. COLLECTOR 2	3. COLLECTOR 1	3. EMITTER	3. ANODE/CATHOD	
4. SOURCE 2	4. EMITTER 2	4. EMITTER 1	4. COLLECTOR	4. ANODE	
5. GATE 2	5. BASE 1	5. BASE 1	5. ANODE	5. CATHODE	
6. DRAIN 1	6. COLLECTOR 1	6. COLLECTOR 2	6. CATHODE	6. COLLECTOR	

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DESCRIPTION:	SC-74		PAGE 1 OF 1	

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0.043

0.004





- XXX = Specific Device Code

(Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering

details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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SC-88/SC70-6/SOT-363 CASE 419B-02 ISSUE Y

DATE 11 DEC 2012

STYLE 1: PIN 1. EMITTER 2 2. BASE 2 3. COLLECTOR 1 4. EMITTER 1 5. BASE 1 6. COLLECTOR 2	STYLE 2: CANCELLED	STYLE 3: CANCELLED	STYLE 4: PIN 1. CATHODE 2. CATHODE 3. COLLECTOR 4. EMITTER 5. BASE 6. ANODE	STYLE 5: PIN 1. ANODE 2. ANODE 3. COLLECTOR 4. EMITTER 5. BASE 6. CATHODE	STYLE 6: PIN 1. ANODE 2 2. N/C 3. CATHODE 1 4. ANODE 1 5. N/C 6. CATHODE 2
STYLE 7: PIN 1. SOURCE 2 2. DRAIN 2 3. GATE 1 4. SOURCE 1 5. DRAIN 1 6. GATE 2	STYLE 8: CANCELLED	STYLE 9: PIN 1. EMITTER 2 2. EMITTER 1 3. COLLECTOR 1 4. BASE 1 5. BASE 2 6. COLLECTOR 2	STYLE 10: PIN 1. SOURCE 2 2. SOURCE 1 3. GATE 1 4. DRAIN 1 5. DRAIN 2 6. GATE 2	STYLE 11: PIN 1. CATHODE 2 2. CATHODE 2 3. ANODE 1 4. CATHODE 1 5. CATHODE 1 6. ANODE 2	STYLE 12: PIN 1. ANODE 2 2. ANODE 2 3. CATHODE 1 4. ANODE 1 5. ANODE 1 6. CATHODE 2
STYLE 13:	STYLE 14:	STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:
PIN 1. ANODE	PIN 1. VREF	PIN 1. ANODE 1	PIN 1. BASE 1	PIN 1. BASE 1	PIN 1. VIN1
2. N/C	2. GND	2. ANODE 2	2. EMITTER 2	2. EMITTER 1	2. VCC
3. COLLECTOR	3. GND	3. ANODE 3	3. COLLECTOR 2	3. COLLECTOR 2	3. VOUT2
4. EMITTER	4. IOUT	4. CATHODE 3	4. BASE 2	4. BASE 2	4. VIN2
5. BASE	5. VEN	5. CATHODE 2	5. EMITTER 1	5. EMITTER 2	5. GND
6. CATHODE	6. VCC	6. CATHODE 1	6. COLLECTOR 1	6. COLLECTOR 1	6. VOUT1
STYLE 19:	STYLE 20:	STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:
PIN 1. I OUT	PIN 1. COLLECTOR	PIN 1. ANODE 1	PIN 1. D1 (i)	PIN 1. Vn	PIN 1. CATHODE
2. GND	2. COLLECTOR	2. N/C	2. GND	2. CH1	2. ANODE
3. GND	3. BASE	3. ANODE 2	3. D2 (i)	3. Vp	3. CATHODE
4. V CC	4. EMITTER	4. CATHODE 2	4. D2 (c)	4. N/C	4. CATHODE
5. V EN	5. COLLECTOR	5. N/C	5. VBUS	5. CH2	5. CATHODE
6. V REF	6. COLLECTOR	6. CATHODE 1	6. D1 (c)	6. N/C	6. CATHODE
STYLE 25:	STYLE 26:	STYLE 27:	STYLE 28:	STYLE 29:	STYLE 30:
PIN 1. BASE 1	PIN 1. SOURCE 1	PIN 1. BASE 2	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. SOURCE 1
2. CATHODE	2. GATE 1	2. BASE 1	2. DRAIN	2. ANODE	2. DRAIN 2
3. COLLECTOR 2	3. DRAIN 2	3. COLLECTOR 1	3. GATE	3. COLLECTOR	3. DRAIN 2
4. BASE 2	4. SOURCE 2	4. EMITTER 1	4. SOURCE	4. EMITTER	4. SOURCE 2
5. EMITTER	5. GATE 2	5. EMITTER 2	5. DRAIN	5. BASE/ANODE	5. GATE 1
6. COLLECTOR 1	6. DRAIN 1	6. COLLECTOR 2	6. DRAIN	6. CATHODE	6. DRAIN 1

Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

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